



Correct as of 15-May-2024 9:21pm For the latest version of our agenda, visit peinternational.net

## Day 1 - Monday 15th April 2024

18:30 Pre-conference networking drinks reception

## Day 2 - Tuesday 16th April 2024

Registration and welcome refreshments

08:00

09:10	Housekeeping by Rob Harper - Conference Chair for the morning session				
Technol	Logy Developments in WBG: SiC, GaN and Beyond Sponsored by SCREEN Semiconductor Solutions Co., Ltd.				
09:20	Aluminum Scandium Nitride (AlScN) a novel material for power electronic applications  Presented by Ali Yassine - University Freiburg				
09:40	Facing SiC Challenges Thanks to UV Laser Annealing Products from SCREEN  Presented by Louis Thuries - SCREEN SPE				
10:00	Cost-effective SiC substrate manufacturing for power devices enabled by oxide-free wafer bonding  Presented by Dr. Bernd Dielacher - EV Group				
10:20	Morning Break				
11:00	SuperGaN's Performance Advantages Challenging SiC's Long-Term Use Presented by Philip Zuk - Transphorm				
11:20	Exploring WBG's technical advances with a glimpse into next UWBG  Presented by Taha Ayari - Yole Group				
11:40	Electronic Packaging Materials for SiC Power Modules  Presented by Dr. Michael Joerger - Heraeus Electronics				
12:00	Gallium Oxide – Taking over from SiC?  Presented by Martin Kuball - University of Bristol				
12:20	Lunch Break				
13:35	Ezgi Dogmus - Conference Chair for afternoon session				
13:35	PowerElec – new metrological tools for quality control of wide bandgap semiconductors  Presented by Sebastian Wood - NPL				
13:55	Novel interconnect and packaging technologies for power module manufacturing  Presented by Huub Claassen - Boschman Advanced Packaging Technology				
14:15	SiC technology optimisation using advanced modelling tools  Presented by Ahmed Nejim - Silvaco				
14:35	Advanced Lapping and polishing processes for SiC Wafers for sustainable and cost effective wafers  Presented by Dr. Ravi Bollina - Pureon AG				
14:55	Afternoon Break				
Silicon MOSFETs and IGBTs: Evolving for the Future					
15:35	High voltage power switch: continuous silicon development as contributor to the green transition  Presented by Antonino Gaito - STMicroelectronics				
15:55	Future developments within IGBTs, and how they may coexist with SiC  Presented by Callum Middleton - Omdia				
16:15	Closing Remarks				
16:20	Networking Drinks / Dinner Reception				

Day 3 - Wednesday 17th April 2024 08:00 Registration and welcome refreshments 09:10 Housekeeping by Denis Marcon - Conference Chair for morning session **System Reliability - Testing Times** SCREEN's Sustainable Cost-of-Ownership (CoO) Portfolio for Thickness Measurement and Wafer Inspection in Power Devices, 09:20 **Automotive, and IoT Applications** Presented by Alessandro Rossi - SCREEN SPE **Enabling Test Automation in Power Electronics Reliability** 09:40 Presented by Andrea Vinci - Tektronix How to Correctly Select a High Definition Oscilloscope and Probe for SiC and GaN Power Device Measurement Accuracy 10:00 Presented by Maurizio Mastrofini - Teledyne LeCroy Capacity Across the Supply Chain The Power Play: Unveiling Capacity Challenges in SiC and GaN Industries 10:20 Presented by Ezgi Dogmus - Yole Group 10:40 Morning Break GaN - Widening the Application Space How to unleash the power savings of GaN in high power, high voltage applications 11:20 Presented by Rupert Baines - QPT New Opportunities for Gallium Nitride in Power, Sensing and RF 11:40 Presented by Rob Harper - Compound Semiconductor Centre Activating GaN's Full Potential with Digital Control for Enhanced Performance Across All Electronics Sectors 12:00 Presented by Thierry Bouchet - Wise Integration Price competitive GaN power devices to enhance performances, shrinking size and lowering cost of power conversion 12:20 solutions  $Presented \ by \ Denis \ Marcon - Innoscience \ Europe \ BV$ GaN is widening the applications field in power electronics 12:40 Presented by Eric Moreau - STMicroelectronics Bi-directional circuits open up new opportunities in off-grid applications 13:00 Presented by Alfred Hesener - Navitas 13:20 Lunch Break Upgrading the GRID – The Role of Power Electronics (inc. Energy Waste and Efficiency)

15:35	Closing Remarks		
15:15	3.3 kV SiC MOSFETs Accelerate Grid-Connected Energy Storage  Presented by Ranbir Singh - Navitas		
14:55	The grid of the future and how SiC power devices will enable the transition towards zero CO2 Presented by Peter Friedrichs - Infineon		
14:35	High-Voltage Silicon Carbide Enables an Omnidirectional Grid  Presented by Kevin Speer - Microchip		
14:35	Peter Friedrichs - Conference Chair for afternoon session		



## **NOTES**